## **Session Program**

29 November 2022 to 2 December 2022



## 41st RD50 Workshop on Radiation Hard Semiconductor Devices for Very High Luminosity Colliders (Sevilla, Spain)

## Low Gain Avalanche Detectors

ETSI Seville, Salón de Grados, 2nd Floor Escuela Técnica Superior de Ingenieros Camino de los Descubrimientos s/n 41092 Isla de la Cartuja, Sevilla Spain

## Thursday 1 December

	Low Gain Avalanche Detectors Session   Location: ETSI Seville, Salón de Grados, 2nd Floor, Escuela Técnica Superior de Ingenieros Camino de los Descubrimientos s/n 41092 Isla de la Cartuja, Sevilla Spain
	09:00-09:20 Spatio-temporal dynamics of charge transport in LGAD probed with focused ion beams Speaker
	Andreo Crnjac 09:20-09:40 Study of 2 P-stop layout of standard segmented LGAD with decreased gain to gain
	distance using TCT-Single Photon Absorption with microscopic resolution enabled by femtosecond laser from ELI Beamlines: Case study of LGAD Type 10 Speaker Gordana Lastovicka Medin
	09:40-10:00 TI-LGAD: beta, test beam and TCT characterization Speaker Matias Senger
	10:00-10:20A two-prong approach to the simulation of DC-RSD: TCAD and SpiceSpeaker Tommaso Croci
25	10:20-10:22 Announcement: Sensors special issue on Radiation Sensors and Detectors" Speakers Michael Moll, Xin Shi
50	Low Gain Avalanche Detectors: Low Gain Avalanche Detectors Session   Location: ETSI Seville, Salón de Grados, 2nd Floor, Escuela Técnica Superior de Ingenieros Camino de los Descubrimientos s/n 41092 Isla de la Cartuja, Sevilla Spain
	10:50-11:10 Update of AC-LGAD at CNM Speaker Neil Moffat
	11:10-11:30   Characterization of neutron- and proton-irradiated LGADs from Teledyne e2v   Speaker   Martin Gazi
	11:30-11:50 Measurements on NLGAD detectors

11:50 Speal	Radiation Tolerance Study of CNM-IMB Run #15246
	Navarrete Ramos
Speal	D-12:30 Study of impact ionization coefficients in Low Gain Avalanche Diode Rer
12:30	0-12:50
	rmination of impact ionization parameters for low gain avalanche detectors uced by HPK
Speal	-
Low Sessio	Gain Avalanche Detectors
	n: ETSI Seville, Salón de Grados, 2nd Floor, Escuela Técnica Superior de Ingenieros Camino de los rimientos s/n 41092 Isla de la Cartuja, Sevilla Spain
	D-14:10 TID study of IHEP-IME LGAD with shallow carbon
<b>Speal</b> Prof. Y	<b>xer</b> unyun Fan
14:10	D-14:30 Deep Junction LGAD: a new approach to high granularity LGAD
<b>Speal</b> Simon	e Michele Mazza
14:30	-14:50 Edge-TCT simulation of LGADs in RASER
<b>Speal</b> Chenx	
14:50	AC-LGADs for 4D reconstruction: from ATLAS to EIC
<b>Speal</b> Gabrie	<b>xer</b> ele D'Amen
Low	Gain Avalanche Detectors
	n   on: ETSI Seville, Salón de Grados, 2nd Floor, Escuela Técnica Superior de Ingenieros Camino de los rimientos s/n 41092 Isla de la Cartuja, Sevilla Spain
15:40	0-16:00
base	Photon Absorption Technique of Transient Current vs Femtosecond Laser d TCT -Single Photon Absorption in the context of the study of LGAD's essing parameters: Casee study of segmented LGADs
Speal	
16:00	0-16:20
charg	arch on LGAD with TCT and laser beam from ELI: Observing the changes in Je transport and in signal formation in Pad and Interpad regions as function ried initially generated charge density

**Speaker** Vanja Backovic

Interpad di technique	stance study on TI-LGAD Wafer 11, using Two-Photon Absorption-TC
Speaker	
•	astovicka-Medin
16:40-17:00	
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Speaker	lage investigation of the and the Low Gain Avalanche Detectors
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Speaker	
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